# On the Measurement of Dislocations and Dislocation Structures using EBSD and HRSD Techniques <br>  

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Full length article
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#### Abstract

The rccumutasion of the selocations and development of diskocition structures in piastically deformed Ne201 is examined using dedicared amilyes of Eletron Back Scamter Dimaction (EBSO) acquired    hiehliptts complementaniy of the two tecteniques when sttemptins to quantify amsunt of platic defirmintion (dimaje) in a minribl va a meacurement of peesent diskcatiums and their structaves  Scatering Domains (CSDS) has been mathematically derived - this allows for an estimntivn of the size of   current resuds supsest that Ashty's sincte-ship mosel underestimates the annuunt of GiNDs (A.C. whife finctiont of imparted plastic stration 


## Dislocations \& Sub-Grain Structure

 which would otherwise appear due to the crystallites (grains) anisotropy are corrected by the storing a portion of dislocations in the form of geometricallynecessary dislocations (GNDs). Plastically deformed material also stores socalled statistically-stored dislocations (SSDs), which are stored by mutual random trapping. Both GNDs and SSDs arrange themselves into energetically favourable configurations, forming geometrically-necessary boundaries (GNBs) and incidental dislocation boundaries (IDBs), respectively.

## Experiment


$\Rightarrow$ EBSD orientation map showing the overall equiaxed grain structure of our solution-annealed Ni201 before testing.

$\Rightarrow$ Interrupted tensile tests were performed to varying levels of imparted plastic strain. Samples were extracted from the gauge length for EBSD and HRSD measurement.

## Ni-201

| Ni | C | Si | P | Fe | Mn | Cr | Mo | $\mathbf{C u}$ | V | Nb | Ti |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| bal. | $<0.01$ | 0.07 | $<0.01$ | 0.03 | $<0.01$ | $<0.01$ | $<0.01$ | 0.01 | $<0.01$ | $<0.01$ | 0.07 |

## EBSD Measurements

## Electron Back-Scatter Diffraction (EBSD)


$\Rightarrow$ EBSD, is a scanning electron microscope (SEM) based technique that gives crystallographic information about the microstructure of a sample.

$\Rightarrow$ The data collected with EBSD is spatially distributed and is visualised in so-called EBSD orientation maps.

## EBSD \& Dislocations


$\Rightarrow$ GNDs have a geometrical consequence giving rise to a curvature of the crystal lattice, which can be measured by EBSD technique. The crystal orientation ( $\phi_{1}, \Phi, \phi_{2}$ ) changes only when the electron beam crosses an array of GNDs that has a net non-zero Burger's vector.

## Lattice Curvature


$\Rightarrow$ A schematic representation of lattice curvature components calculation between two neighbouring crystals misoriented $(\Delta \theta)$ by a rotation around the common crystallographic axis $[100]_{c}\left([u v w]_{c}\right)$ and separated by pixel separation distance $\left(\Delta \mathrm{x}_{2}\right)$. Note, that in this example: $\kappa_{12} \approx \Delta \theta_{1} / \Delta \mathrm{x}_{2}$, and $\kappa_{22}, \kappa_{32}=0$.

## Lattice Curvature Tensor


pixel separation distance, $\Delta \mathbf{x}$

Lattice Curvature Tensor Components

$$
\kappa_{11} \approx \frac{\Delta \theta_{1}}{\Delta x_{1}} ; \kappa_{21} \approx \frac{\Delta \theta_{2}}{\Delta x_{1}} ; \kappa_{31} \approx \frac{\Delta \theta}{\Delta x_{1}}
$$

$$
\kappa_{12} \approx \frac{\Delta \theta_{1}}{\Delta x_{2}} ; \kappa_{22} \approx \frac{\Delta \theta_{2}}{\Delta x_{2}} ; \kappa_{32} \approx \frac{\Delta}{\Delta x_{2}}
$$

## Lattice Curvature \& GND Density


$N=1$.. 36 - number ofpossible dislocation types

## Burgers Vector

$\left.\begin{array}{l}\text { Edge Dislocations: } 12 \\ \text { Screw Dislocations: } 6\end{array}\right\}$
Dislocation Types: $2 \times 18=36$
dislocations of opposite
sign needs to be distinguished

## 1,947,792 possibilities!

$\left[\begin{array}{c}\kappa_{11} \\ \kappa_{21} \\ \kappa_{31} \\ \kappa_{12} \\ \kappa_{22} \\ \kappa_{32}\end{array}\right]=\left[\begin{array}{cccc}\frac{1}{2} b_{1}^{1} l_{1}^{1} & \frac{1}{2} b_{1}^{2} l_{1}^{2} & \cdots & \frac{1}{2} b_{1}^{36} l_{1}^{36} \\ b_{1}^{1} l_{2}^{1} & b_{1}^{2} l_{2}^{2} & \cdots & b_{1}^{36} l_{2}^{36} \\ b_{1}^{1} l_{3}^{1} & b_{1}^{2} l_{3}^{2} & \cdots & b_{1}^{36} l_{3}^{36} \\ b_{2}^{1} l_{1}^{1} & b_{2}^{2} l_{1}^{2} & \cdots & b_{2}^{36} l_{1}^{36} \\ \frac{1}{2} b_{2}^{1} l_{2}^{1} & \frac{1}{2} b_{2}^{2} l_{2}^{2} & \cdots & \frac{1}{2} b_{2}^{36} l_{2}^{36} \\ b_{2}^{1} l_{3}^{1} & b_{2}^{2} l_{3}^{2} & \cdots & b_{2}^{36} l_{3}^{36}\end{array}\right]\left[\begin{array}{c}\rho_{\mathrm{G}}^{1} \\ \rho_{\mathrm{G}}^{2} \\ \vdots \\ \vdots \\ \rho_{\mathrm{G}}^{36}\end{array}\right]$

6 known lattice curvatures (measured)

36 possible dislocation types

## Dislocation Types (fcc)



## Lower-Bound GND Density



Burgers Vector
Edge Dislocations: 12

Dislocation Types: $2 \times 18=36$
dislocations of opposite sign needs to be distinguished

## 1,947,792 possibilities!

$\left[\begin{array}{c}\kappa_{11} \\ \kappa_{21} \\ \kappa_{31} \\ \kappa_{12} \\ \kappa_{22} \\ \kappa_{32}\end{array}\right]=\left[\begin{array}{cccc}\frac{1}{2} b_{1}^{1} l_{1}^{1} & \frac{1}{2} b_{1}^{2} l_{1}^{2} & \cdots & \frac{1}{2} b_{1}^{36} l_{1}^{36} \\ b_{1}^{1} l_{2}^{1} & b_{1}^{2} l_{2}^{2} & \cdots & b_{1}^{36} l_{2}^{36} \\ b_{1}^{1} l_{3}^{1} & b_{1}^{2} l_{3}^{2} & \cdots & b_{1}^{36} l_{3}^{36} \\ b_{2}^{1} l_{1}^{1} & b_{2}^{2} l_{1}^{2} & \cdots & b_{2}^{36} l_{1}^{36} \\ \frac{1}{2} b_{2}^{1} l_{2}^{1} & \frac{1}{2} b_{2}^{2} l_{2}^{2} & \cdots & \frac{1}{2} b_{2}^{36} l_{2}^{36} \\ b_{2}^{1} l_{3}^{1} & b_{2}^{2} l_{3}^{2} & \cdots & b_{2}^{36} l_{3}^{36}\end{array}\right]\left[\begin{array}{c}\rho_{\mathrm{G}}^{1} \\ \rho_{\mathrm{G}}^{2} \\ \vdots \\ \vdots \\ \rho_{\mathrm{G}}^{36}\end{array}\right]$

6 known lattice curvatures (measured)

36 possible dislocation types
Lower-bound GND Density

$$
\rho_{G}=\sum_{t=1}^{36} \rho_{G}^{t} \approx \min \sum_{t=1}^{6} \rho_{G}^{t}
$$

Not all dislocation types are

## GND Density


$\Rightarrow$ Density of geometrically-necessary dislocations (GND, $\rho_{G}$ ) maps calculated from the EBSD-measured Euler Angles ( $\phi_{1}, \Phi, \phi_{2}$ ) for specimens with $0 \%$ (as-received), $7.8 \%$ and $13.9 \%$ of imparted plastic strain.
$\Rightarrow$ Step size ( h ) $=200 \mathrm{~nm}$
$\Rightarrow$ Magnification $=153 x$
$\Rightarrow$ Discrete measurements provide information on spatial distribution of GND across the microstructure.
$\Rightarrow$ GNDs arrange themselves into energetically favourable configurations forming geometricallynecessary boundaries (GNBs) subdividing grains into the sub-grains.

## GND Spacing


$\Rightarrow$ Spacing between geometrically-necessary dislocations (GND, $\mathrm{d}_{\mathrm{G}}$ ) recalculated from the GND density $\left(\rho_{G}\right)$ for specimens with $0 \%$ (as-received), $7.8 \%$ and $13.9 \%$ of imparted plastic strain.
$\Rightarrow$ Non-uniform distribution of GNDs in the microstructure as GNDs arrange themselves into energetically favourable configurations subdividing grains into the sub-grains.


## GND Density - High Resolution


$\Rightarrow$ Density of geometrically-necessary dislocations (GND, $\rho_{G}$ ) calculated from the EBSD-measured Euler Angles ( $\phi_{1}, \Phi, \phi_{2}$ ).

$$
\begin{aligned}
& \Rightarrow \text { Step size }(\mathrm{h})=20 \mathrm{~nm} \\
& \Rightarrow \text { Magnification }=1000 \mathrm{x}
\end{aligned}
$$


$\Rightarrow$ Spacing between geometrically-necessary dislocations (GND, $\mathrm{d}_{\mathrm{G}}$ ) recalculated from the GND density $\left(\rho_{\mathrm{G}}\right)$.

## GND Density



## Microstructure-Averaged GND Density


$\Rightarrow$ Distribution (histogram) of discrete GND density $\left(\rho_{G}\right)$ measurements for specimen with 0\% (as-received), $7.8 \%$ and $13.9 \%$ of imparted plastic strain $\left(\varepsilon_{\mathrm{p}}\right)$.

Log-Normal Distribution

$$
f\left(\rho_{G} \mid \mu, \sigma\right)=\frac{1}{x \sigma \sqrt{2 \pi}} \exp \left(\frac{-\left(\ln \left(\rho_{G}\right)-\mu\right)^{2}}{2 \sigma^{2}}\right)
$$

MEAN of the lognormal distribution

## Mean \& Variance

$\overbrace{m}\left(\rho_{G}\right)=\exp \left(\mu+\frac{\sigma^{2}}{2}\right)$

$$
v\left(\rho_{G}\right)=\exp \left(2 \mu+\sigma^{2}\right)\left(\exp \left(\sigma^{2}\right)\right.
$$

VARIANCE of the lognormal distribution
$\Rightarrow$ The variance of the GND density distribution describes the heterogeneity of the GND distribution across variously oriented grains within the microstructure, the mean can be then taken as the microstructure-averaged (bulk) GND density.

## Microstructure-Averaged GND Density


$\Rightarrow$ The development of the mean GND density as a function of number of analysed grains in GND density maps for specimen with $0 \%$ (as-received), $7.8 \%$ and 13.9\% of imparted plastic strain $\left(\varepsilon_{\mathrm{p}}\right)$.

Log-Normal Distribution

$$
f\left(\rho_{G} \mid \mu, \sigma\right)=\frac{1}{x \sigma \sqrt{2 \pi}} \exp \left(\frac{-\left(\ln \left(\rho_{G}\right)-\mu\right)^{2}}{2 \sigma^{2}}\right)
$$

MEAN of the log- Mean \& Variance

$$
\underbrace{\text { normal distribution }} m\left(\rho_{G}\right)=\exp \left(\mu+\frac{\sigma^{2}}{2}\right)
$$

$$
v_{\pi}^{v}\left(\rho_{G}\right)=\exp \left(2 \mu+\sigma^{2}\right)\left(\exp \left(\sigma^{2}\right)\right.
$$

VARIANCE of the lognormal distribution
$\Rightarrow$ Due to the increase in heterogeneity of GND distribution with imparted plastic strain, a larger number of grains is required to reach solution convergence.

## Microstructure-Averaged GND Density


$\Rightarrow$ The development of the mean GND density distribution as a function of imparted plastic strain $\left(\varepsilon_{p}\right)$ for all tested specimens.

$\Rightarrow$ The development of the variance of GND density distribution as a function of imparted plastic strain $\left(\varepsilon_{p}\right)$ for all tested specimens.

## GND Types in Solution



| 0 | 0.1 | 0.2 | 0.3 | 0.4 | 0.5 | 0.6 | 0.7 | 0.8 | 0.9 | 1.0 |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
|  |  |  | Screw GNDs Ratio |  |  |  |  |  |  |  |

$\Rightarrow$ Map showing the ratio of screw dislocations to the total number of dislocations in the solution (6) for the specimen with $13.9 \%$ imparted plastic strain.

$\Rightarrow$ Screw dislocation ratio as a function of imparted plastic strain for all tested specimens.
$\Rightarrow$ The uniqueness of the solution is not guaranteed. $\Rightarrow$ Only pure edge and pure screw dislocations have been considered in the calculation.

## HRSD Measurements

## HRSD Set-Up


$\Rightarrow$ High-resolution synchrotron diffraction (HRSD) set-up at 1-ID
 high-energy beamline at the Advanced Photon Source (APS), Argonne National Laboratory (ANL).

## Diffraction Peak Broadening

$\Rightarrow$ The total diffraction peak shape (which includes peak broadening) $I_{\text {TOTAL }}$ of a is the convolution of the shape contribution caused by the size of coherently scattering domains (sub-grains) $I_{\text {SIZE }}$ and the contribution caused by strain fields of present dislocations $I_{\text {STRAIN }}$.
$\Rightarrow$ Convolution is defined as the invers Fourier transform of the product of the individual Fourier transform of the components.

$$
I_{\text {TOTAL }}=I_{\text {SIZE }} * I_{\text {STRAIN }}=\mathcal{F}^{-1}\left(A^{\text {Size }} A^{\text {Strain }}\right)
$$




## Diffraction Peak Broadening



$\Rightarrow$ The broadening due to the size of the coherently diffracting domains (sub-grains) is the same for all hkl diffraction peaks, while the broadening component due to the strain field of present dislocations varies between diffraction peaks. This variation in the strain (dislocation) broadening is not monotonous due to the anisotropic behaviour described by the dislocation contrast factors.

## Diffraction Peak Broadening

$\Rightarrow 2 \mathrm{D}$ diffraction pattern (Debye-Scherrer rings) of specimen with $13.9 \%$ of imparted plastic strain.


$\Rightarrow$ Comparison of full diffraction patterns for specimens with 0\% (as-received) and $13.9 \%$ of imparted plastic strain. The different behavior of size (sub-grain) and strain (dislocation) peak broadening can be resolved if many peaks are available.
$\Rightarrow$ The diffraction peak broadening was analysed using the eCMWP (extended Convolutional Multiple Whole Profile) LPA software

## Total Dislocation Density \& Sub-Grain Size


$\Rightarrow$ Total dislocation density $\left(\rho_{\mathrm{T}}\right)$ and size of the coherently scattering domains (SCDs) obtained by line profile analysis (LPA) of HRSD patterns as a function of imparted plastic strain $\left(\varepsilon_{\mathrm{p}}\right)$ - open symbols represents individual measurements along the sample loading axis, and solid symbol represents the mean values.

## EBSD + HRSD Measurements

## EBSD- \& HRSD- Measured Dislocation Density



$\Rightarrow$ Comparison of the HRND-measured total dislocation density ( $\rho_{\mathrm{T}}$ ) and the EBSD-measured density of GNDs ( $\rho_{\mathrm{G}}$ ), together with expected dislocation densities calculated using the modified Taylor's model, and single-slip Ashby's model.

## GND Density \& Size of CSDs


$\Rightarrow$ Comparison of the HRSD-measured size of CSDs (red circles) with EBSD-measured spacing of GNDs ( $\mathrm{d}_{\mathrm{G}}$ ) (blue squares), and the estimated minimum size of CSDs (green triangles) from EBSD-measured density of GNDs $\left(\rho_{\mathrm{G}}\right)$.

$\Rightarrow$ This defines the connection between EBSDmeasured $\rho_{G}$ and HRSD-measured $\langle X\rangle_{A}$ one can then estimate $\rho_{G}$ from $\langle X\rangle_{A}$.

## Conclusions

$\Rightarrow$ EBSD measures the lower-bound $\rho_{G}$, while HRSD measures $\rho_{T}$.
$\Rightarrow$ The minimum detected $\rho_{T}$ measured by HRSD is about $1 E 13 \mathrm{~m}^{-2}$, while the minimum $\rho_{G}$ measured by EBSD is about $2 \mathrm{E} 12 \mathrm{~m}^{-2}$.
$\Rightarrow$ EBSD is more sensitivity to the small amount of plastic deformation in the material, while HRSD gets more accurate with higher amount of plastic deformation.
$\Rightarrow$ There is a connection between EBSD-measured $\rho_{G}$ and HRSD-measured size of CSDs $\left(\langle X\rangle_{A}\right)$.
$\Rightarrow$ EBSD $=$ Density of GNDs $\left(\rho_{G}\right)$, + estimate the minimum Size of CSDs
$\Rightarrow$ HRSD $=$ Total Dislocation Density $\left(\rho_{T}\right)$, size of $\operatorname{CSDs}\left(\langle X\rangle_{A}\right)$, + estimate of minimum density of GNDs $\left(\rho_{G}\right)$


## Thank you for your time and interest in this work. We hope you will find it useful.

